

March 1998 Revised October 2004

#### 74VCX16601

# **Low Voltage 18-Bit Universal Bus Transceivers** with 3.6V Tolerant Inputs and Outputs

#### **General Description**

The VCX16601 is an 18-bit universal bus transceiver which combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs. The clock can be controlled by the clock-enable (CLKENAB and CLKENBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a HIGH-to-LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the LOW-to-HIGH transition of CLKAB. When OEAB is LOW, the outputs are active. When OEAB is HIGH, the outputs are in the high-impedance state.

<u>Data flow</u> for B to A is similar to that of A to B but uses <u>OEBA</u>, LEBA, CLKBA and <u>CLKENBA</u>.

The VCX16601 is designed for low voltage (1.4V to 3.6V)  $V_{CC}$  applications with I/O capability up to 3.6V.

The VCX16601 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

#### **Features**

- $\blacksquare$  1.4V to 3.6V  $V_{CC}$  supply operation
- 3.6V tolerant inputs and outputs
- t<sub>PD</sub> (A to B, B to A)
  2.9 ns max for 3.0V to 3.6V V<sub>CC</sub>
- Power-down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- Static Drive (I<sub>OH</sub>/I<sub>OL</sub>)
  - ±24 mA @ 3.0V V<sub>CC</sub>
- Uses patented noise/EMI reduction circuitry
- Latchup performance exceeds 300 mA
- ESD performance:

Human body model > 2000V

Machine model >200V

■ Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA) (Preliminary)

Note 1:  $\underline{\mathsf{To}}$  ensure the high-impedance state during power up or power down, OE should be tied to  $V_{CC}$  through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

#### **Ordering Code:**

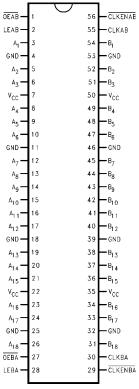
Order Number	Package Number	Package Description
74VCX16601GX (Note 2)		54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide [TAPE and REEL]
74VCX16601MTD (Note 3)	MTD56	56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Note 2: BGA package available in Tape and Reel only.

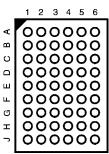
Note 3: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

#### **Connection Diagrams**

Pin Assignment for TSSOP



Pin Assignment for FBGA



(Top Thru View)

#### **Pin Descriptions**

Pin Names	Description
OEAB, OEBA	Output Enable Inputs (Active LOW)
LEAB, LEBA	Latch Enable Inputs
CLKAB, CLKBA	Clock Inputs
CLKENAB, CLKENBA	Clock Enable Inputs
A <sub>1</sub> -A <sub>18</sub>	Side A Inputs or 3-STATE Outputs
B <sub>1</sub> -B <sub>18</sub>	Side B Inputs or 3-STATE Outputs

#### **FBGA Pin Assignments**

	1	2	3	4	5	6
Α	A <sub>2</sub>	A <sub>1</sub>	OEAB	CLKENAB	B <sub>1</sub>	B <sub>2</sub>
В	A <sub>4</sub>	A <sub>3</sub>	LEAB	CLKAB	В3	B <sub>4</sub>
С	A <sub>6</sub>	A <sub>5</sub>	V <sub>CC</sub>	V <sub>CC</sub>	B <sub>5</sub>	В <sub>6</sub>
D	A <sub>8</sub>	A <sub>7</sub>	GND	GND	B <sub>7</sub>	B <sub>8</sub>
E	A <sub>10</sub>	A <sub>9</sub>	GND	GND	B <sub>9</sub>	B <sub>10</sub>
F	A <sub>12</sub>	A <sub>11</sub>	GND	GND	B <sub>11</sub>	B <sub>12</sub>
G	A <sub>14</sub>	A <sub>13</sub>	V <sub>CC</sub>	V <sub>CC</sub>	B <sub>13</sub>	B <sub>14</sub>
Н	A <sub>16</sub>	A <sub>15</sub>	OEBA	CLKBA	B <sub>15</sub>	B <sub>16</sub>
J	A <sub>17</sub>	A <sub>18</sub>	LEBA	CLKENBA	B <sub>18</sub>	B <sub>17</sub>

#### **Truth Table**

(Note 4)

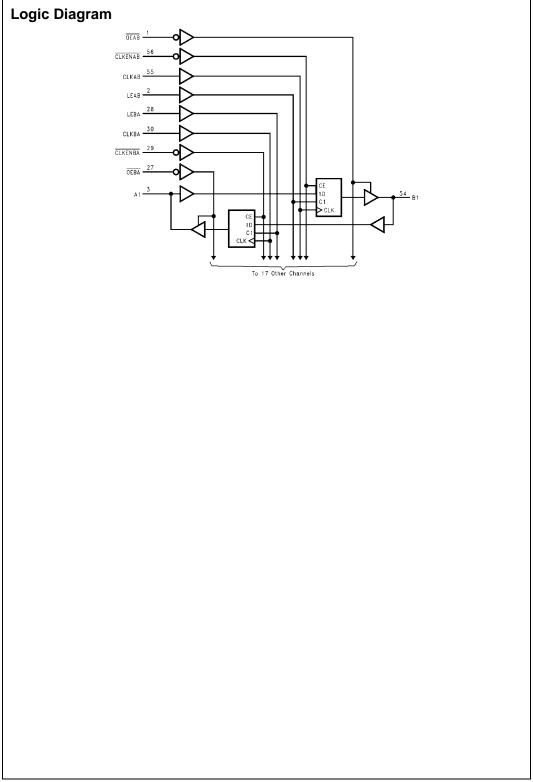
	Inputs				Outputs
CLKENAB	OEAB	LEAB	CLKAB	A <sub>n</sub>	B <sub>n</sub>
Х	Н	Х	Х	Χ	Z
Х	L	Н	X	L	L
Х	L	Н	X	Н	Н
Н	L	L	X	Χ	B <sub>0</sub> (Note 5)
Н	L	L	X	Χ	B <sub>0</sub> (Note 5)
L	L	L	$\uparrow$	L	L
L	L	L	$\uparrow$	Н	Н
L	L	L	L	Χ	B <sub>0</sub> (Note 5)
L	L	L	Н	Χ	B <sub>0</sub> (Note 6)

- H = HIGH Voltage Level
- L = LOW Voltage Level
- X = Immaterial (HIGH or LOW, inputs may not float)
  Z = High Impedance

Note 4: A-to-B data flow is shown; B-to-A flow is similar but uses  $\overline{\text{OEBA}}$ , LEBA, CLKBA, and  $\overline{\text{CLKENBA}}$ .

Note 5: Output level before the indicated steady-state input conditions were established.

Note 6: Output level before the indicated steady-state input conditions were established, provided that CLKAB was HIGH before LEAB went LOW.



#### **Absolute Maximum Ratings**(Note 7)

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Outputs Active (Note 8)  $-0.5 \text{ to V}_{CC} + 0.5 \text{V}$  DC Input Diode Current (I $_{IK}$ ) V $_{I}$  < 0V -50 mA

DC Output Diode Current (I<sub>OK</sub>)

 $V_{O} < 0V$  -50 mA  $V_{O} > V_{CC}$  +50 mA

DC Output Source/Sink Current

 $(I_{OH}/I_{OL})$  ±50 mA

DC  $V_{CC}$  or Ground Current per

Supply Pin (I $_{CC}$  or Ground)  $\pm 100$  mA Storage Temperature Range (T $_{STG}$ )  $-65^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$ 

## Recommended Operating Conditions (Note 9)

Power Supply

Operating 1.4V to 3.6V Input Voltage -0.3V to 3.6V

Output Voltage (V<sub>O</sub>)

Output in Active States 0V to  $V_{CC}$  Output in 3-STATE 0.0V to 3.6V

Output Current in  $I_{OH}/I_{OL}$ 

 $V_{CC} = 3.0V \text{ to } 3.6V$  ±24 mA

 $\begin{array}{ll} \text{V}_{CC} = 2.3 \text{V to } 2.7 \text{V} & \pm 18 \text{ mA} \\ \text{V}_{CC} = 1.65 \text{V to } 2.3 \text{V} & \pm 6 \text{ mA} \end{array}$ 

 $V_{CC} = 1.4V \text{ to } 1.6V$   $\pm 2 \text{ mA}$ 

-40°C to +85°C

Free Air Operating Temperature ( $T_A$ ) Minimum Input Edge Rate ( $\Delta t/\Delta V$ )

 $V_{IN} = 0.8V \text{ to } 2.0V, V_{CC} = 3.0V$  10 ns/V

Note 7: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The Recommended Operating Conditions tables will define the conditions for actual device operation.

Note 8: IO Absolute Maximum Rating must be observed.

Note 9: Floating or unused pin (inputs or I/O's) must be held HIGH or LOW.

#### **DC Electrical Characteristics**

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	Min	Max	Units
V <sub>IH</sub>	HIGH Level Input Voltage		2.7 - 3.6	2.0		
			2.3 - 2.7	1.6		V
			1.65 - 2.3	0.65 x V <sub>CC</sub>		V
			1.4 - 1.6	0.65 x V <sub>CC</sub>		
V <sub>IL</sub>	LOW Level Input Voltage		2.7 - 3.6		0.8	
			2.3 - 2.7		0.7	V
			1.65 - 2.3		0.35 - V <sub>CC</sub>	V
			1.4 - 1.6		0.35 - V <sub>CC</sub>	
V <sub>OH</sub>	HIGH Level Output Voltage	$I_{OH} = -100 \ \mu A$	2.7 - 3.6	V <sub>CC</sub> - 0.2		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		
		$I_{OH} = -18 \text{ mA}$	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
		$I_{OH} = -100 \mu A$	2.3 - 2.7	V <sub>CC</sub> - 0.2		
		$I_{OH} = -6 \text{ mA}$	2.3	2.0		V
		$I_{OH} = -12 \text{ mA}$	2.3	1.8		V
		$I_{OH} = -18 \text{ mA}$	2.3	1.7		
		$I_{OH} = -100 \mu A$	1.65 - 2.3	V <sub>CC</sub> - 0.2		
		$I_{OH} = -6 \text{ mA}$	1.65	1.25		
		$I_{OH} = -100 \mu A$	1.4 - 1.6	V <sub>CC</sub> - 0.2		
		$I_{OH} = -2 \text{ mA}$	1.4	1.05		

## DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V <sub>CC</sub>	Min	Max	Units
1			(V)			
V <sub>OL</sub>	LOW Level Output Voltage	$I_{OL} = 100 \mu A$	2.7 - 3.6		0.2	
		I <sub>OL</sub> = 12 mA	2.7		0.4	
		I <sub>OL</sub> = 18 mA	3.0		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.55	
		$I_{OL} = 100 \mu A$	2.3 - 2.7		0.2	
		I <sub>OL</sub> = 12 mA	2.3		0.4	V
		I <sub>OL</sub> = 18 mA	2.3		0.6	
		$I_{OL} = 100 \mu A$	1.65 - 2.3		0.2	<u> </u>
		I <sub>OL</sub> = 6 mA	1.65		0.3	
		$I_{OL} = 100 \mu A$	1.4 - 1.6		0.2	
		I <sub>OL</sub> = 2 mA	1.4		0.35	
I <sub>I</sub>	Input Leakage Current	0V ≤ V <sub>I</sub> ≤ 3.6V	2.7 - 3.6		±5.0	μΑ
I <sub>OZ</sub>	3-STATE Output Leakage	0V ≤ V <sub>O</sub> ≤ 3.6V	1.4 - 3.6		±10.0	μА
	$V_{l} = V_{lH}$ or $V_{lL}$	1.4 - 3.0		±10.0	μΑ	
I <sub>OFF</sub>	Power Off Leakage Current	$0V \le (V_I, V_O) \le 3.6V$	0		10.0	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>I</sub> = V <sub>CC</sub> or GND	1.4 - 3.6		20.0	
		$V_{CC} \le (V_I, V_O) \le 3.6V \text{ (Note 10)}$	1.4 - 3.6		±20.0	μΑ
$\Delta I_{CC}$	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	2.7 - 3.6		750	μΑ

Note 10: Outputs disabled or 3-STATE only.

## AC Electrical Characteristics (Note 11)

Symbol	Parameter	Conditions	V <sub>CC</sub>	$T_A = -40^{\circ}C \text{ to} + 85^{\circ}C$		Units	Figure
Syllibol		Conditions	(V)	Min	Max		Number
f <sub>MAX</sub>	Maximum Clock Frequency	C <sub>L</sub> = 30 pF	$3.3 \pm 0.3$	250			
			$2.5 \pm 0.2$	200		MHz	
			$1.8 \pm 0.15$	100		IVII IZ	
		C <sub>L</sub> = 15 pF	1.5 ± 0.1	80.0			
t <sub>PHL</sub>	Propagation Delay	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$3.3 \pm 0.3$	8.0	2.9		Figures 1
t <sub>PLH</sub>	Bus-to-Bus		$2.5 \pm 0.2$	1.0	3.5		Figures 1, 2
			$1.8 \pm 0.15$	1.5	7.0	ns	
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	14.0		Figures 7, 8
t <sub>PHL</sub>	Propagation Delay	$C_L = 30 \text{ pF, } R_L = 500\Omega$	$3.3 \pm 0.3$	0.8	3.5		
t <sub>PLH</sub>	Clock-to-Bus		$2.5 \pm 0.2$	1.0	4.4		Figures 1,
			$1.8 \pm 0.15$	1.5	8.8	ns	_
		$C_L = 15 \text{ pF}, R_L = 500\Omega$	1.5 ± 0.1	1.0	17.6		Figures 7,
t <sub>PHL</sub>	Propagation Delay	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3	0.8	3.5		
t <sub>PLH</sub>	LE-to-Bus		2.5 ± 0.2	1.0	4.4		Figures 1,
			1.8 ± 0.15	1.5	8.8	ns	2
		$C_L = 15 \text{ pF}, R_L = 500\Omega$	1.5 ± 0.1	1.0	17.6		Figures 7,
t <sub>PZL</sub>	Output Enable Time	$C_L = 30 \text{ pF}, R_L = 500\Omega$	3.3 ± 0.3	0.8	3.8		
t <sub>PZH</sub>			$2.5 \pm 0.2$	1.0	4.9		Figures 1, 3, 4
			$1.8 \pm 0.15$	1.5	9.8	ns	,
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	19.6		Figures 7, 9, 10
t <sub>PLZ</sub>	Output Disable Time	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$3.3 \pm 0.3$	0.8	3.7		Figure 4
t <sub>PHZ</sub>			$2.5 \pm 0.2$	1.0	4.2		Figures 1, 3, 4
			$1.8 \pm 0.15$	1.5	7.6	ns	,
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	15.2		Figures 7, 9, 10
t <sub>S</sub>	Setup Time	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$3.3 \pm 0.3$	1.5			
			$2.5 \pm 0.2$	1.5		ns	Figure 6
			$1.8 \pm 0.15$	2.5		115	i iguie o
		$C_L = 15 \text{ pF}, R_L = 500\Omega$	1.5 ± 0.1	3.0			
t <sub>H</sub>	Hold Time	$C_L = 30 \text{ pF, } R_L = 500\Omega$	$3.3 \pm 0.3$	1.0			
			$2.5 \pm 0.2$	1.0		ns	Figure 6
			$1.8 \pm 0.15$	1.0		113	i iguic o
		$C_L = 15 \text{ pF}, R_L = 500\Omega$	1.5 ± 0.1	2.0			
t <sub>W</sub>	Pulse Width	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$3.3 \pm 0.3$	1.5			
			$2.5 \pm 0.2$	1.5		ns	Figure 5
			$1.8 \pm 0.15$	4.0			1.9
		$C_L = 15 \text{ pF}, R_L = 500\Omega$	1.5 ± 0.1	4.0			
t <sub>OSHL</sub>	Output to Output Skew	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$3.3 \pm 0.3$		0.5		
t <sub>OSLH</sub>	(Note 12)		$2.5 \pm 0.2$		0.5	ns	
			$1.8 \pm 0.15$		0.75		
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1	1.5		

Note 11: For  $C_L = 50pF$ , add approximately 300ps to the AC maximum specification.

Note 12: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>).

## **Dynamic Switching Characteristics**

Symbol	Parameter	Conditions	V <sub>CC</sub>	$T_A = +25^{\circ}C$	Units
	T drameter	Conditions	(V)	Typical	Onico
V <sub>OLP</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V <sub>OLV</sub>	Quiet Output Dynamic Valley V <sub>OL</sub>	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.25	
			2.5	-0.6	V
			3.3	-0.8	
V <sub>OHV</sub>	Quiet Output Dynamic Valley V <sub>OH</sub>	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

## Capacitance

Symbol	Parameter	Conditions	$T_A = +25^{\circ}C$	Units
C <sub>IN</sub>	Input Capacitance	V <sub>I</sub> = 0V or V <sub>CC</sub> V <sub>CC</sub> = 1.8V, 2.5V, or 3.3V	6.0	pF
C <sub>I/O</sub>		V <sub>I</sub> = 0V or V <sub>CC</sub> , V <sub>CC</sub> = 1.8V, 2.5V or 3.3V	7.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance	V <sub>I</sub> = 0V or V <sub>CC</sub> , f = 10 MHz V <sub>CC</sub> = 1.8V, 2.5V or 3.3V	20.0	pF

## AC Loading and Waveforms (V $_{CC}$ 3.3V $\pm$ 0.3V to 1.8V $\pm$ 0.15V)

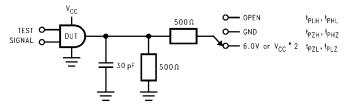
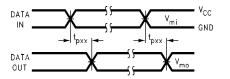


FIGURE 1. AC Test Circuit

TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	6V at $V_{CC} = 3.3V \pm 0.3V$ ; $V_{CC} \times 2$ at $V_{CC} = 2.5V \pm 0.2V$ ; $1.8V \pm 0.15V$
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND



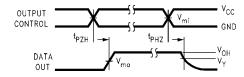


FIGURE 2. Waveform for Inverting and Non-inverting Functions

FIGURE 3. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

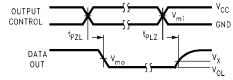
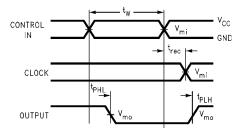


FIGURE 4. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic



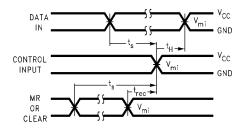
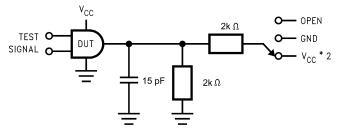


FIGURE 5. Propagation Delay, Pulse Width and  $$t_{\rm rec}$$  Waveforms

FIGURE 6. Setup Time, Hold Time and Recovery Time for Low Voltage Logic

Symbol		V <sub>CC</sub>	
- Cymbol	$3.3V \pm 0.3V$	2.5V ± 0.2V	1.8V ± 0.15V
V <sub>mi</sub>	1.5V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
$V_{mo}$	1.5V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
V <sub>X</sub>	$V_{OL} + 0.3V$	V <sub>OL</sub> + 0.15V	V <sub>OL</sub> + 0.15V
V <sub>Y</sub>	V <sub>OH</sub> – 0.3V	V <sub>OH</sub> – 0.15V	V <sub>OH</sub> – 0.15V

## AC Loading and Waveforms (V $_{CC}$ 1.5V $\pm$ 0.1V)



 $t_{PLH}, t_{PHL}$   $t_{PZH}, t_{PHZ}$   $t_{PZI}, t_{PIZ}$ 

TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
t <sub>PZL</sub> , t <sub>PLZ</sub>	$V_{CC}$ x 2 at $V_{CC} = 1.5 \pm 0.1$ V
t <sub>PZH</sub> , t <sub>PHZ</sub>	GND

FIGURE 7. AC Test Circuit

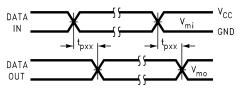


FIGURE 8. Waveform for Inverting and Non-inverting Functions

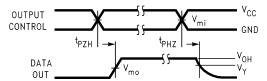


FIGURE 9. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

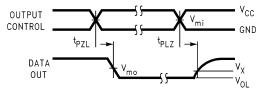
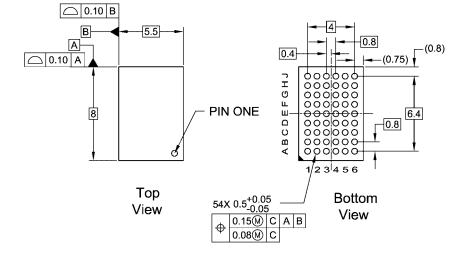
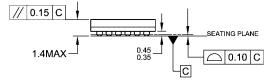


FIGURE 10. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic

Symbol	V <sub>CC</sub>
	1.5V ± 0.1V
$V_{mi}$	V <sub>CC</sub> /2
V <sub>mo</sub>	V <sub>CC</sub> /2
V <sub>X</sub>	V <sub>OL</sub> + 0.1V
$V_{Y}$	V <sub>OH</sub> – 0.1V

## Physical Dimensions inches (millimeters) unless otherwise noted



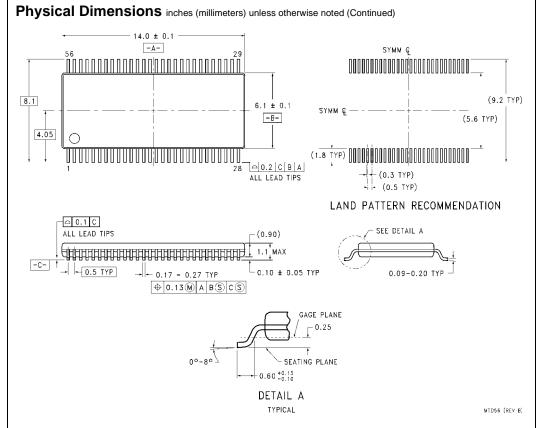


#### NOTES:

- A. THIS PACKAGE CONFORMS TO JEDEC M0-205
- **B. ALL DIMENSIONS IN MILLIMETERS**
- C. LAND PATTERN RECOMMENDATION: NSMD (Non Solder Mask Defined)
  .35MM DIA PADS WITH A SOLDERMASK OPENING OF .45MM CONCENTRIC TO PADS
  D. DRAWING CONFORMS TO ASME Y14.5M-1994

#### BGA54ArevD

54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide Package Number BGA54A (Preliminary)



56-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD56

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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